## NSN 5961-01-199-0385

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-199-0385 **Inclosure Material:** Metal **Overall Length:** 0.785 inches **Overall Height:** 0.185 inches Overall Width: Between 0.220 inches and 0.310 inches **Component Name And Quantity:** 16 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 55.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 350.00 milliamperes forward current, dc all semiconductor device diode **Power Rating Per Characteristic:** 650.0 milliwatts total power dissipation all semiconductor device diode **Capacitance Rating In Picofarads:** 5.0 all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 12 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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